preliminary

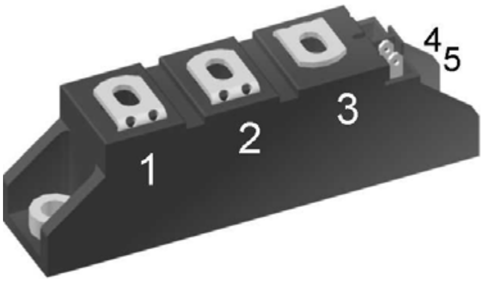
Thyristor Module

V_{RRM}	=	2x 1200 V
I_{TAV}	=	85 A
V_T	=	1.18 V

Phase leg

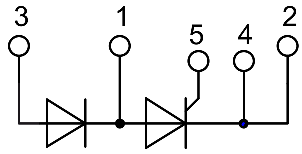
Part number

MCMA85PD1200TB



Backside: isolated

E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

 Data according to IEC 60747and per semiconductor unless otherwise specified 20130109a

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Thyristor				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM/DSM}$	*max. non-repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1300	V
$V_{RRM/DRM}$	*max. repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1200	V
$I_{R/D}$	*reverse current, drain current*	$V_{R/D}$ = 1200 V	T_{VJ} = 25°C			100	µA
		$V_{R/D}$ = 1200 V	T_{VJ} = 140°C			10	mA
V_T	*forward voltage drop*	I_T = 85 A	T_{VJ} = 25°C			1.21	V
		I_T = 170 A				1.47	V
		I_T = 85 A	T_{VJ} = 125°C			1.18	V
		I_T = 170 A				1.51	V
I_{TAV}	*average forward current*	T_C = 85°C	T_{VJ} = 140°C			85	A
$I_{T(RMS)}$	*RMS forward current*	180° sine				135	A
V_{T0}	*threshold voltage*	*for power loss calculation only*	T_{VJ} = 140°C			0.85	V
r_T	*slope resistance*					3.9	mΩ
R_{thJC}	*thermal resistance junction to case*					0.38	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.20		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			300	W
I_{TSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			1.50	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.62	kA
		t = 10 ms; (50 Hz), sine	T_{VJ} = 140°C			1.28	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.38	kA
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			11.3	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			10.9	kA²s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 140°C			8.13	kA²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			7.87	kA²s
C_J	*junction capacitance*	V_R = 400 V f = 1 MHz	T_{VJ} = 25°C		74		pF
P_{GM}	*max. gate power dissipation*	t_P = 30 µs	T_C = 140°C			10	W
		t_P = 300 µs				5	W
P_{GAV}	*average gate power dissipation*					0.5	W
$(di/dt)_{cr}$	*critical rate of rise of current*	T_{VJ} = 140°C; f = 50 Hz	repetitive, I_T = 255 A			150	A/µs
		t_P = 200 µs; di_G/dt = 0.45 A/µs;					
		I_G = 0.45 A; V_D = ⅔ V_{DRM}	non-repet., I_T = 85 A			500	A/µs
$(dv/dt)_{cr}$	*critical rate of rise of voltage*	V_D = ⅔ V_{DRM}	T_{VJ} = 140°C			1000	V/µs
		R_{GK} = ∞; method 1 (linear voltage rise)					
V_{GT}	*gate trigger voltage*	V_D = 6 V	T_{VJ} = 25°C			1.5	V
			T_{VJ} = -40°C			1.6	V
I_{GT}	*gate trigger current*	V_D = 6 V	T_{VJ} = 25°C			95	mA
			T_{VJ} = -40°C			200	mA
V_{GD}	*gate non-trigger voltage*	V_D = ⅔ V_{DRM}	T_{VJ} = 140°C			0.2	V
I_{GD}	*gate non-trigger current*					10	mA
I_L	*latching current*	t_p = 10 µs	T_{VJ} = 25°C			200	mA
		I_G = 0.45 A; di_G/dt = 0.45 A/µs					
I_H	*holding current*	V_D = 6 V R_{GK} = ∞	T_{VJ} = 25°C			200	mA
t_{gd}	*gate controlled delay time*	V_D = ½ V_{DRM}	T_{VJ} = 25°C			2	µs
		I_G = 0.45 A; di_G/dt = 0.45 A/µs					
t_q	*turn-off time*	V_R = 100 V; I_T = 85 A; V_D = ⅔ V_{DRM}	T_{VJ} = 140°C		150		µs
		di/dt = 10 A/µs; dv/dt = 20 V/µs; t_p = 200 µs					

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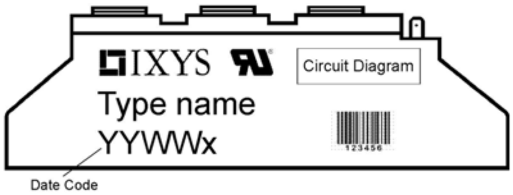
Package TO-240AA				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I_{RMS}	*RMS current*	per terminal				200	A
T_{stg}	*storage temperature*			-40		125	°C
T_{VJ}	*virtual junction temperature*			-40		140	°C
Weight					90		g
M_D	*mounting torque*			2.5		4	Nm
M_T	*terminal torque*			2.5		4	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*	*terminal to terminal*	13.0	9.7			mm
$d_{Spb/Apb}$		*terminal to backside*	16.0	16.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA	4800			V
		t = 1 minute		4000			V



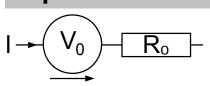
Part number

M	=	Module
C	=	Thyristor (SCR)
M	=	Thyristor
A	=	(up to 1800V)
85	=	Current Rating [A]
PD	=	Phase leg
1200	=	Reverse Voltage [V]
TB	=	TO-240AA-1B

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA85PD1200TB	MCMA85PD1200TB	Box	6	513043

Equivalent Circuits for Simulation

** on die level* T_{VJ} = 140°C



Thyristor

$V_{0\,max}$	*threshold voltage*	0.85	V
$R_{0\,max}$	*slope resistance **	2.7	mΩ

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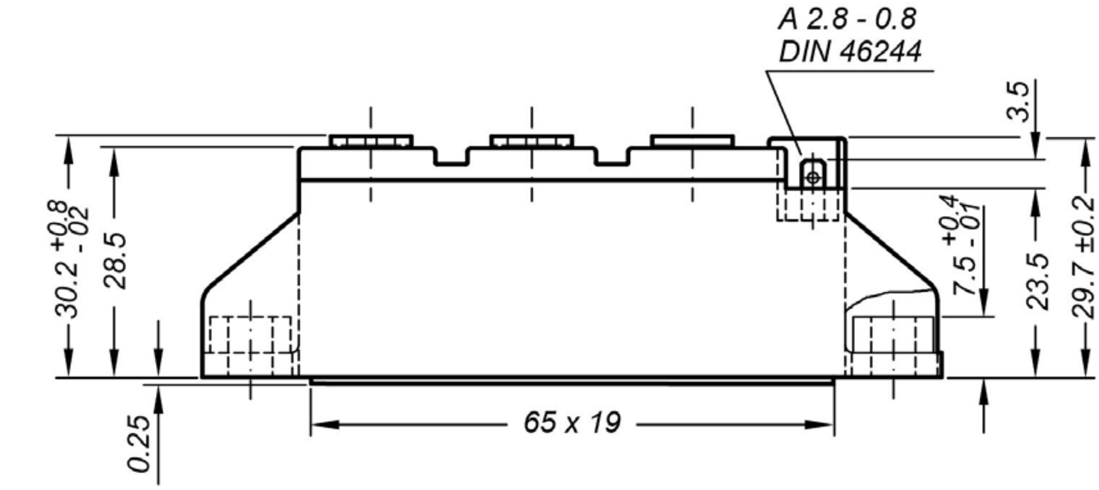
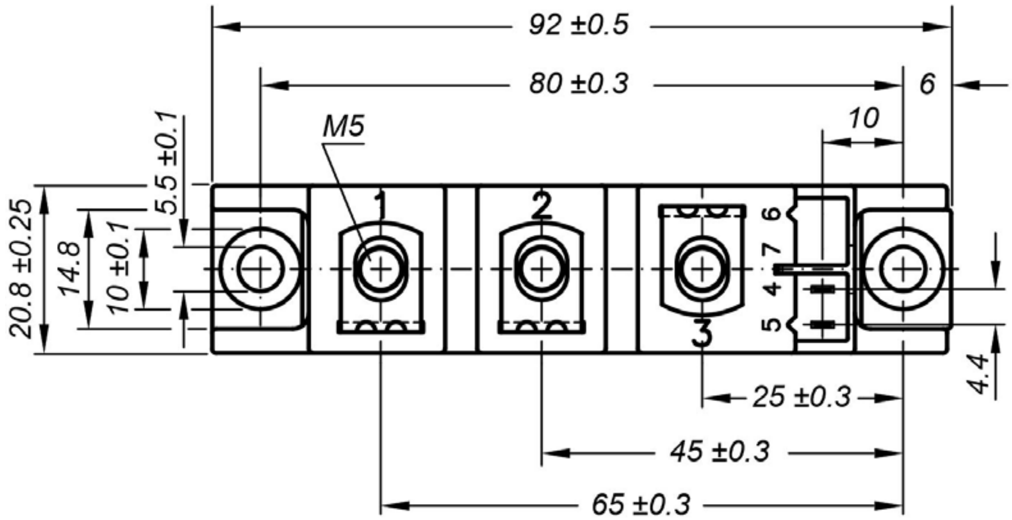
Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c“



Optional accessories: Keyed gate/cathode twin plugs
Wire length: 350 mm, gate = white, cathode = red
UL 758, style 3751
*Type **ZY 200L** (L = Left for pin pair 4/5)*